EXAS RUMENTS Data sheet acquired from Harris Semiconductor SCHS104C - Revised October 2003

CMOS Hex 'D'-Type Flip-Flop

High-Voltage Types (20-Volt Rating)

CD40174B consists of six identical 'D'-type flip-flops having independent DATA inputs. The CLOCK and CLEAR inputs are common to all six units. Data is transferred to the Q outputs on the positive-going transition of the clock pulse. All six flip-flops are simultaneously reset by a low level on the CLEAR input.

The CD40174B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, MT, and NSR suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (VDD)
Voltages referenced to V _{SS} Terminal)
INPUT VOLTAGE RANGE, ALL INPUTS
DC INPUT CURRENT, ANY ONE INPUT ±10mA
POWER DISSIPATION PER PACKAGE (PD):
For $T_A = -55^{\circ}C$ to $+100^{\circ}C$
For T _A = +100°C to +125°C Derate Linearity at 12mW/°C to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR T _A = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)
OPERATING-TEMPERATURE RANGE (T _A)
STORAGE TEMPERATURE RANGE (Tsta)

STORAGE LEAR ENAN	She holde (i sig)	
LEAD TEMPERATURE	(DURING SOLDERING):	

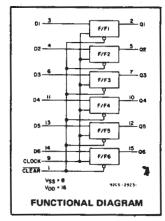
At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max +265°C

Features:

- = 5-V, 10-V, and 15-V parametric rating
- Standardized symmetrical output characteristics
- = 100% tested for quiescent current at 20 V
- Maximum input current of 1 µA at 18 V
- over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (over full package-temperature range): 1 V at V_{DD} = 5 V 2 V at V_{DD} = 10 V 2.5 V at V_{DD} = 15 V

- Meets all requirements of JEDEC Tentative Standard No. 13A, "Standard Specifications for Description of 'B' Series CMOS Devices"

CD40174B Types



Applications:

- Shift Registers
- Buffer/Storage Registers
- Pattern Generators

TRUTH TABLE FOR 1 OF 6 FLIP-FLOPS

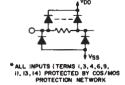
	OUTPUT		
CLOCK	DATA	CLEAR	٥
	0	1	0
	1	1	1
2	×	1	NC
X	×	0	0

1 = High Level 0 = Low Level

-09 10.12.15)

9205-2983

X = Don't Care NC = No Change





CL

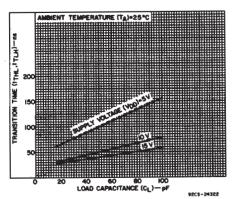
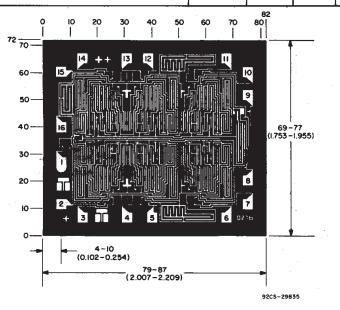
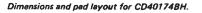


Fig. 2- Typical transition time as a function of load capacitance.

RECOMMENDED OPERATING CONDITIONS at $T_A = 25^{\circ}C$, Except as Noted. For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	V _{DD}	LIN	UNITS	
	(V)	Min.	Max.	1
Supply-Voltage Range (For T _A = Full Package-			40	
Temperature Range)		3	18	V
	5	40	-	
Data Setup Time, t _{SU}	10	20	- 1	ns
	15	10	-	
	5	80	-	
Data Hold Time, t _H	10	40	-	ns
	15	30	-	
	5		3.5	1
Clock Input Frequency, f _{CL}	10	dc	6	MHz
	15		8	
	5	· _	15	
Clock Input Rise or Fall Time, trCL, trCL	10	. –	15	μs
	15	-	15	
	5	130	- 1	
Clock Input Pulse Width, tWL, tWH	10	60	-	ns
	15	40	- 1	
**************************************	5	100	-	
Clear Pulse Width, twL	10	50	-	ns
•••	15	40	-	
	5	0	-	
Clear Removal Time, tREM	10	0	-	ns
	15	0	· · ·	





Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch) .

The photographs and dimensions of each CMOS chip represent a chip when it is part of the wefer. When the wafer is separated into individual chips, the angle of cleavage may vary with respect to the chip face for different chips. The actual dimensions of the isolated chip, therefore, may differ slightly from the nominal dimensions shown. The user should consider a tolerance of -3 mils 10 +16 mila applicable to the nominal dimensions shown.

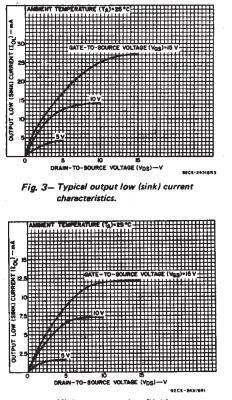
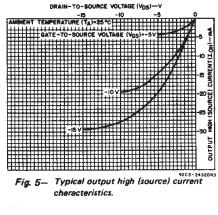
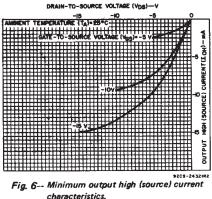


Fig. 4— Minimum output low (sink) current characteristics.

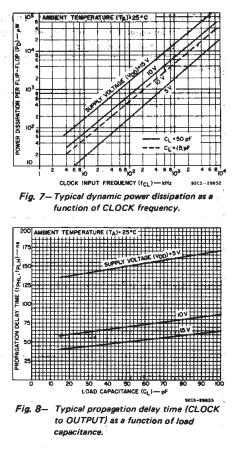


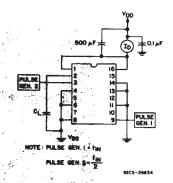


3

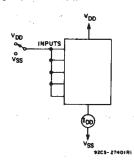
STATIC ELECTRICAL CHARACTERISTICS

CHARAC-	CONI	οιτιο	NS	LIMITS AT INDICATED TEMPERATURES (°C)						. ¹ 2	UN
TERISTIC	Vo	VIN	V _{DD}				a cert		+25		Ι ΄
	(V)	(V)	(V)-	-55	40	+85	+125	Min.	Тур.	Max.	S
Quiescent	_	0,5	5	1	1	30	30	-	0.02	1	
Device	· _	0,10	10	2	2	60	60	-	0.02	2]μ/
Current, fDD		0,15	15	4	4	120	120	-	0.02	4	
Max.	n i n	0,20	20	20	20	600	600	-	0.04	20]
Output Low (Sink)	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	-	
Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	-]
I _{OL} Min.	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	-	
Output High (Source)	4.6	0,5	5	0.64	-0.61	-0.42	-0.36	-0.51	-1]_m/
	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	-]
Current,	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	2.6		
IOH Min.	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	6.8		1
Output Voltage:	- <u>-</u> 1	0,5	5		0	.05	_	0	0.05		
Low-Level,	 . :	0,10	10		0	.05		3	0.05]	
V _{OL} Max.	. 	0,15	15		0	.05	<u> </u>	0	0.05],	
Output Voltage:	— · :	0,5	5	4.95 4.95					5	_	ľ
High-Level,	-	0,10	10		9	.95	9,95	10]	
V _{OH} Min.	-	0,15	15		14	.95		14.95	15	-	
Input Low	0.5,4.5	1	5		1	.5			-	1.5	
Voltage,	1,9	_	10	3						3	
VIL Max.	1.5,13.5		15			4		-	-	4],
Inpuț High	0.5,4.5	_	5.			8.5		3.5			
Voltage,	1,9		10	7 7					·		
V _{IH} Min.	1.5,13.5	-	15			11		11	-	² –	
Input Current † _{IN} Max.		0,18	18	±0.1	±0.1	±1	±1	- 3	±10 ⁻⁵	±0.1	μA





Dynamic power dissipation test circuit. 當



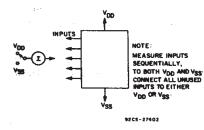
1, CL 'DD CLOCK 10% /00 DATA INPUT - 50% SULLH)* SUGHE TTLH THU /D0 90% OUTPUT 10 % *PLH - 1PHL *(LH) OR (HL) OPTIONAL REN CLEAR -50% 9203-2006984

Fig. 10- Definition of setup, hold, propagation delay, and removal times.

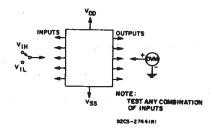
Fig. 11 - Quiescent device current test circuit.

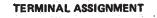
CHARACTERISTIC		TEST CONDITIONS		UNITS		
		V _{DD} (V)	Min.	Тур.	Max.	
Proposition Dalay Tim	- (5		150	300	
Propagation Delay Tim		10	_	70	140	ns .
Clock to Output,	^t PHL ^{, t} PLH	15	_	50	100	
		5	-	100	200	<i>,</i> '
Clear to Output,	^t PHL	10	-	50	100	ns
		15	_	40	80	1
		5		100	200	
Transition Time,	^t THL ^{, t} TLH	10	-	50	100	ns
		15	_	40	80	
Minimum Pulse Width.		5	-	65	130	· ·
Clock,		10	_	30	60	ns
CIOCK,	^t WL ^{, t} WH	15	_	20	40	
	÷ 1.	5		50	100	
Clear,	twl	10	· · _	25	50	ns
		15	_	20	40	
		5		20	40	
Minimum Data Setup T	ime, t _{SU}	10	-	10	20	ns
	00	15	-	0	10	
		5	_	40	80	
Minimum Data Hold Ti	me, t _H	10	-	20	40	ns
	••	15	-	15	30	
	····	5	3.5	7	_	
Maximum Clock Frequ	ency, f _{CI}	10	6	12		MHz
·	UL	15	- 8	16		
		5 and 5	15	3 <u> </u>	1-1-1	
Maximum Clock Rise o	r Fall	10	15	· – .	- 1	μs
Time, t _r CL, t _f CL		15	15	- **	<u> </u>	
Input Capacitance, CIN	4					
Clear		-	_	25	40	pF
All other		-	_	5	7.5]
Minimum Clear Remov		5	_	-40	0	
		10		15	o	ns
Time,	15	_	-10	0		

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A = 25^{\circ}C$; Input t_p , $t_f = 20$ ns, $C_L = 50$ pF, $R_L = 200$ k Ω



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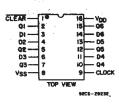




Fig. 13 - Input voltage test circuit.

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CD40174BE	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD40174BF	ACTIVE	CDIP	J	16	1	TBD	Call TI	Level-NC-NC-NC
CD40174BF3A	ACTIVE	CDIP	J	16	1	TBD	Call TI	Level-NC-NC-NC
CD40174BM	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40174BM96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40174BM96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40174BME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40174BMT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40174BMTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40174BNSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40174BNSRE4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40174BPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40174BPWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40174BPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40174BPWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE OPTION ADDENDUM



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J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



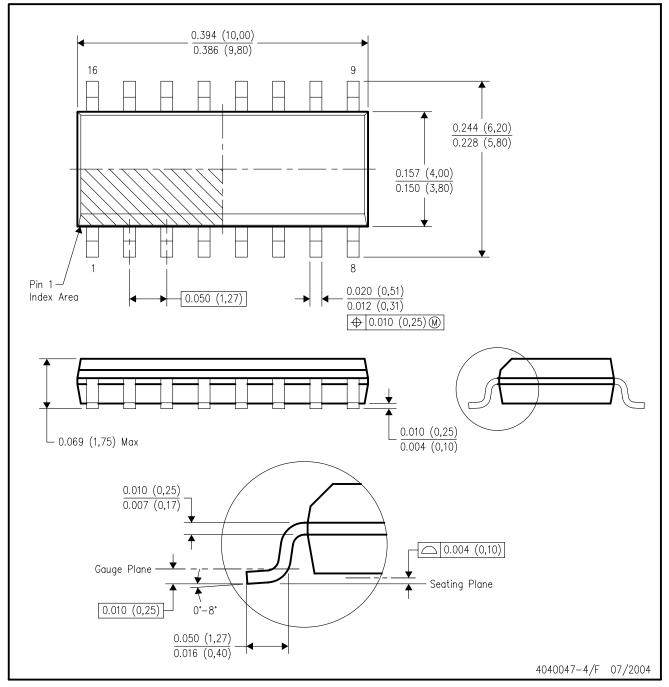
NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012 variation AC.



MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 \bigcirc Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS ** 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G**)

14-PINS SHOWN

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



MECHANICAL DATA

MTSS001C - JANUARY 1995 - REVISED FEBRUARY 1999

PW (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



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Mailing Address:

Texas Instruments

Post Office Box 655303 Dallas, Texas 75265

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